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# P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY	
V <sub>DS</sub> (V)	- 20
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.032
$R_{DS(on)}(\Omega)$ at $V_{GS} = -2.5 \text{ V}$	0.052
$R_{DS(on)}(\Omega)$ at $V_{GS} = -1.8 \text{ V}$	0.065
I <sub>D</sub> (A)	- 6
Configuration	Single

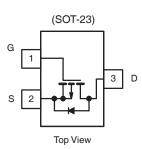
#### **FEATURES**

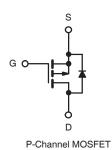
- Halogen-free Option Available
- TrenchFET® Power MOSFET



#### **APPLICATIONS**

• Load Switch for Portable Devices





ABSOLUTE MAXIMUM RATING	GS (T <sub>C</sub> = 25 °C, unles	s otherwise noted	d)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		$V_{DS}$	- 20		
Gate-Source Voltage		$V_{GS}$	± 8	V	
Continuous Drain Current	T <sub>C</sub> = 25 °C	- I <sub>D</sub>	- 6		
	T <sub>C</sub> = 125 °C		- 4		
Continuous Source Current (Diode Conduction)		I <sub>S</sub>	- 3.5	Α	
Pulsed Drain Current <sup>a</sup>		I <sub>DM</sub>	- 20		
Single Pulse Avalanche Current	. 0.4	I <sub>AS</sub>	- 12		
Single Pulse Avalanche Energy	L = 0.1 mH	E <sub>AS</sub>	6	mJ	
Maximum Power Dissipation <sup>a</sup>	T <sub>C</sub> = 25 °C	D	2	10/	
	T <sub>C</sub> = 125 °C	$P_{D}$	0.67	W	
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>sta</sub>	- 55 to + 175	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	LIMIT	UNIT	
Junction-to-Ambient	PCB Mount <sup>b</sup>	$R_{thJA}$	175	°C/W	
Junction-to-Foot (Drain)		R <sub>thJF</sub>	75	C/VV	

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PARAMETER	SYMBOL	TES	TEST CONDITIONS		TYP.	MAX.	UNIT	
Static	1	<b>'</b>			1			
Drain-Source Breakdown Voltage	V <sub>DS</sub>	V <sub>GS</sub> = 0 V, I <sub>D</sub> = - 250 μA		- 20	-	-		
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = - 250 μA		-	- 2	V	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$		-	-	± 100	nA	
Zero Gate Voltage Drain Current		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = - 12 V	-	-	- 1		
	I <sub>DSS</sub>	V <sub>GS</sub> = 0 V	V <sub>DS</sub> = - 12 V, T <sub>J</sub> = 125 °C	-	-	- 50	μА	
		V <sub>GS</sub> = 0 V	V <sub>DS</sub> = - 12 V, T <sub>J</sub> = 175 °C	-	-	- 150		
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	V <sub>GS</sub> = - 4.5 V	V <sub>DS</sub> ≤ - 5 V	- 10	-	-	Α	
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = - 4.5 V	I <sub>D</sub> = - 3.5 A	-	0.032	-	Ω	
		V <sub>GS</sub> = - 4.5 V	I <sub>D</sub> = - 3.5 A, T <sub>J</sub> = 125 °C	-	0.047	-		
	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 4.5 V	I <sub>D</sub> = - 3.5 A, T <sub>J</sub> = 175 °C	-	0.049	-		
		V <sub>GS</sub> = - 2.5 V	I <sub>D</sub> = - 3 A	-	0.052	-		
		V <sub>GS</sub> = - 1.8 V	I <sub>D</sub> = - 1 A	-	0.065	-		
Forward Transconductanceb	9 <sub>fs</sub>	V <sub>DS</sub> =	- 5 V, I <sub>D</sub> = - 1.6 A	-	7	-	S	
Dynamic <sup>b</sup>								
Input Capacitance	C <sub>iss</sub>		V <sub>GS</sub> = 0 V V <sub>DS</sub> = -6 V, f = 1 MHz	-	695	890	pF	
Output Capacitance	Coss	$V_{GS} = 0 V$		-	265	345		
Reverse Transfer Capacitance	C <sub>rss</sub>			-	190	250		
Total Gate Charge <sup>c</sup>	Qg			-	8.4	13		
Gate-Source Charge <sup>c</sup>	$Q_{gs}$	$V_{GS} = -4.5 \text{ V}$	V <sub>DS</sub> = -6 V, I <sub>D</sub> = -3.85 A	-	1	-	nC	
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>	7		-	2.4			
Gate Resistance	R <sub>g</sub>	f = 1 MHz		4.1	8.2	13.3	Ω	
Turn-On Delay Time <sup>c</sup>	t <sub>d(on)</sub>			-	17	26		
Rise Time <sup>c</sup>	t <sub>r</sub>	$V_{DD} = -6 \text{ V}, R_L = 1.6 \Omega$ $I_D \cong -3.85 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		-	19	29	- ns	
Turn-Off Delay Time <sup>c</sup>	t <sub>d(off)</sub>			-	28	42		
Fall Time <sup>c</sup>	t <sub>f</sub>			-	13	20		
Source-Drain Diode Ratings and Char	acteristics <sup>b</sup>							
Pulsed Current <sup>a</sup>	I <sub>SM</sub>			-	-	- 20	Α	
Forward Voltage	V <sub>SD</sub>	I <sub>F</sub> = - 2 A, V <sub>GS</sub> = 0 V		-	- 0.8	- 1.2	V	

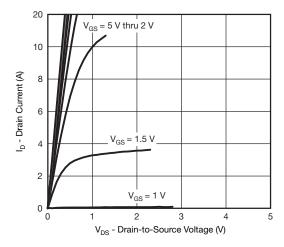
#### Notes

- a. Pulse test; pulse width  $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

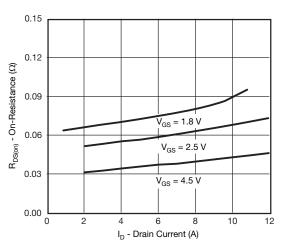
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



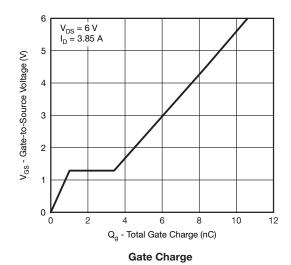
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)

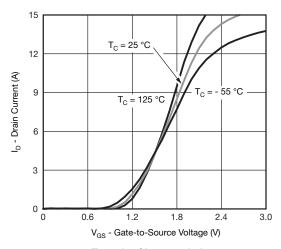


#### **Output Characteristics**

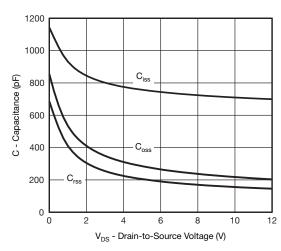


On-Resistance vs. Drain Current

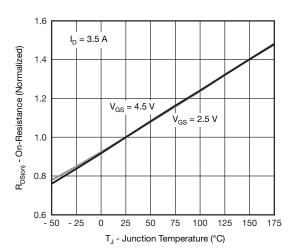




**Transfer Characteristics** 



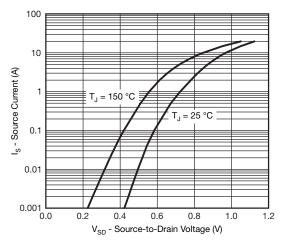
Capacitance



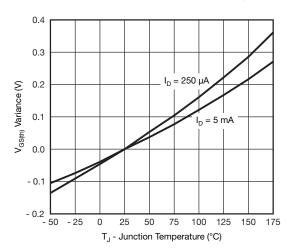
On-Resistance vs. Junction Temperature



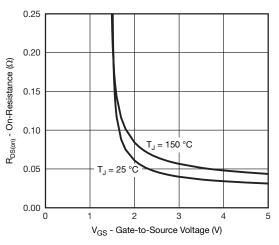
### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



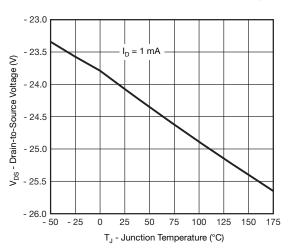
### Source-Drain Diode Forward Voltage



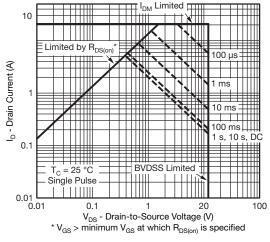
**Threshold Voltage** 



On-Resistance vs. Gate-to-Source Voltage



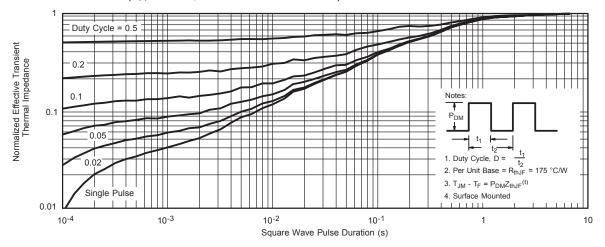
**Drain Source Breakdown vs. Junction Temperature** 



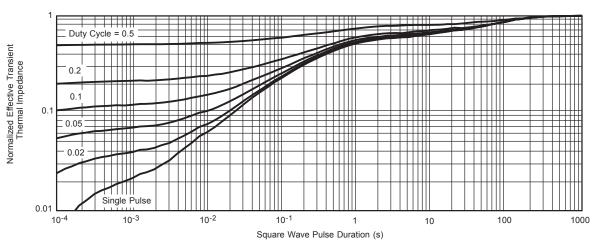
Safe Operating Area



### THERMAL RATINGS (T<sub>A</sub> = 25 °C, unless otherwise noted)



#### Normalized Thermal Transient Impedance, Junction-to-Foot



Normalized Thermal Transient Impedance, Junction-to-Ambient

#### Note

- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction-to-Foot (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.



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